Power MOSFET -60 V, 16 mΩ, -60 A, P-Channel

Automotive Power MOSFET designed for compact and efficient designs and including high thermal performance.

 $AEC\mbox{-}Q101$ qualified MOSFET and PPAP capable suitable for automotive applications.



- Low On-Resistance
- High Current Capability
- 100% Avalanche Tested
- AEC-Q101 qualified and PPAP capable
- ATPAK package is pin-compatible with DPAK (TO-252)
- Pb-Free, Halogen Free and RoHS compliance

Typical Applications

- Reverse Battery Protection
- Load Switch
- Automotive Front Lighting
- Automotive Body Controllers

SPECIFICATIONS

ABSOLUTE MAXIMUM RATING at Ta = 25°C (Note 1)

Parameter	Symbol	Value	Unit	
Drain to Source Voltage	VDSS	-60	V	
Gate to Source Voltage	VGSS	±20	V	
Drain Current (DC)	lD	-60	Α	
Drain Current (Pulse) PW ≤ 10 μs, duty cycle ≤ 1%	IDP	-180	Α	
Power Dissipation Tc = 25°C	PD	72	W	
Operating Junction and Storage Temperature	Tj, Tstg	-55 to +175	°C	
Avalanche Energy (Single Pulse) (Note 2)	EAS	100	mJ	
Avalanche Current (Note 3)	lΑV	-28	Α	
Note 1 : Ctroppes eveneding those listed in the Maximum Datings table may demage				

Note 1: Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

- 2 : V_{DD} = -15 V, L = 200 μ H, I_{AV} = -28 A
- 3 : L ≤ 100 μ H, Single pulse

THERMAL RESISTANCE RATINGS

Parameter	Symbol	Value	Unit		
Junction to Case Steady State (Tc = 25°C)	R ₀ JC	2.0	°C/W		
Junction to Ambient (Note 4)	R_{θ} JA	79.6	°C/W		

Note 4: Surface mounted on FR4 board using a 130 mm², 1 oz. Cu pad.

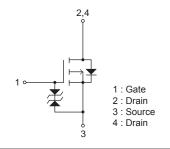


ON Semiconductor®

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VDSS	R _{DS} (on) Max	ID Max
	16 mΩ @ –10 V	
-60 V	21 mΩ @ -4.5 V	-60 A
	24 mΩ @ –4 V	

ELECTRICAL CONNECTION P-Channel





MARKING



ORDERING INFORMATION

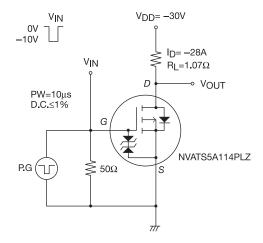
See detailed ordering and shipping information on page 6 of this data sheet.

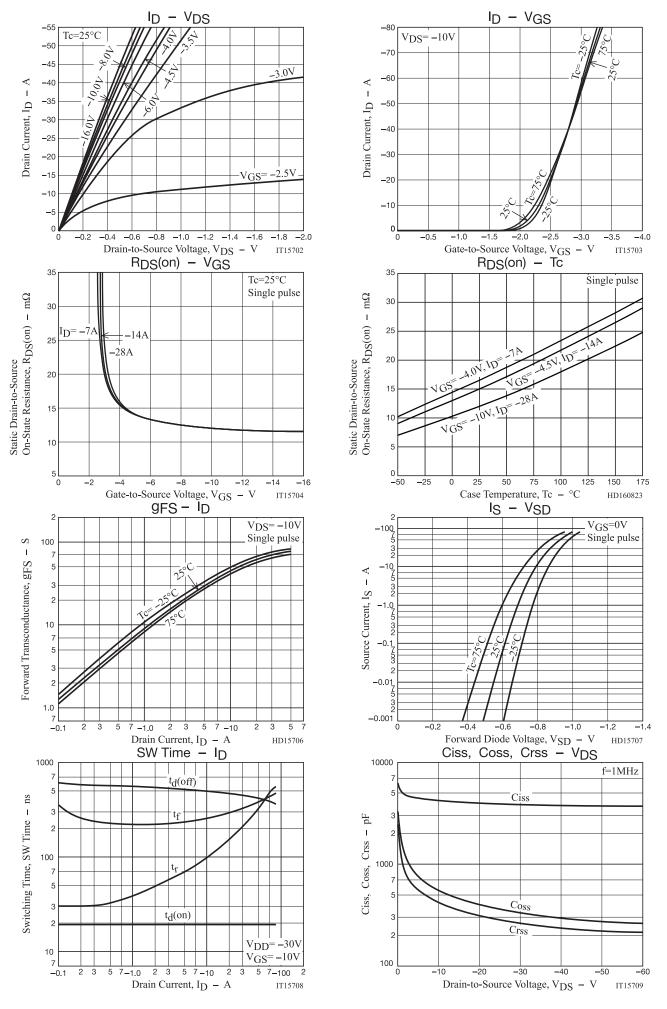
ELECTRICAL CHARACTERISTICS at Ta = 25°C (Note 5)

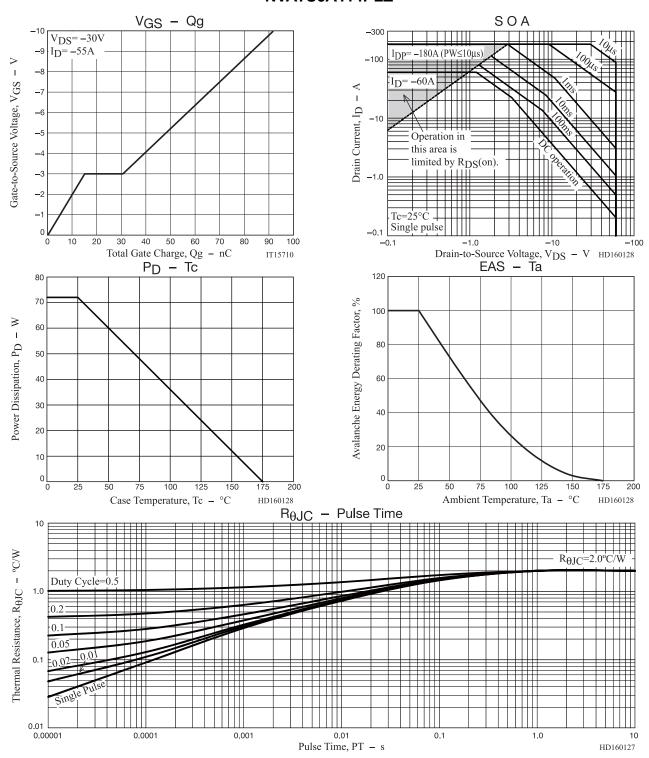
Parameter	Cumbal	Conditions	Value			Unit
Parameter	Symbol	Conditions	min	typ	max	Unit
Drain to Source Breakdown Voltage	V(BR)DSS	I _D = -1 mA, V _{GS} = 0 V	-60			V
Zero-Gate Voltage Drain Current	IDSS	V _{DS} = -60 V, V _{GS} = 0 V			-1	μΑ
Gate to Source Leakage Current	IGSS	$V_{GS} = \pm 16 \text{ V}, V_{DS} = 0 \text{ V}$			±10	μΑ
Gate Threshold Voltage	V _{GS} (th)	$V_{DS} = -10 \text{ V}, I_{D} = -1 \text{ mA}$	-1.2		-2.6	V
Forward Transconductance	gFS .	$V_{DS} = -10 \text{ V}, I_{D} = -28 \text{ A}$		65		S
Static Drain to Source On-State Resistance	R _{DS} (on)1	I _D = -28 A, V _{GS} = -10 V		12	16	mΩ
	R _{DS} (on)2	I _D = -14 A, V _{GS} = -4.5 V		15	21	mΩ
	RDS(on)3	I _D = -7 A, V _{GS} = -4 V		16.5	24	mΩ
Input Capacitance	Ciss			4,000		pF
Output Capacitance	Coss	$V_{DS} = -20 \text{ V, f} = 1 \text{ MHz}$		400		pF
Reverse Transfer Capacitance	Crss			315		pF
Turn-ON Delay Time	t _d (on)			19		ns
Rise Time	t _r	See Fig. 1		200		ns
Turn-OFF Delay Time	t _d (off)	See Fig.1		450		ns
Fall Time	tf			300		ns
Total Gate Charge	Qg			92		nC
Gate to Source Charge	Qgs	$V_{DS} = -30 \text{ V}, V_{GS} = -10 \text{ V}, I_{D} = -55 \text{ A}$		15		nC
Gate to Drain "Miller" Charge	Qgd			15.5		nC
Forward Diode Voltage	V _{SD}	I _S = -55 A, V _{GS} = 0 V		-0.95	-1.5	V

Note 5 : Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

Fig.1 Switching Time Test Circuit







ORDERING INFORMATION

ONDERING INFORMATION			
Device	Marking	Package	Shipping (Qty / Packing)
NVATS5A114PLZT4G	ATP114	DPAK(Single Gauge) / ATPAK (Pb-Free / Halogen Free)	3,000 / Tape & Reel

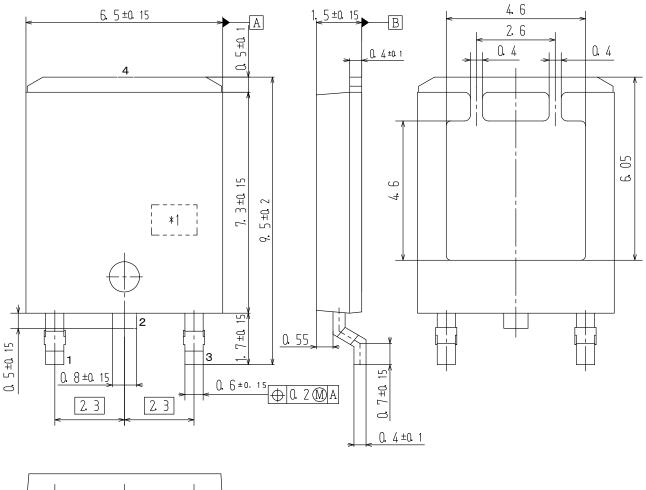
[†] For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D. http://www.onsemi.com/pub_link/Collateral/BRD8011-D.PDF

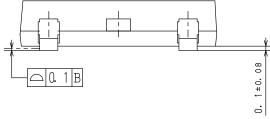
Note on usage : Since the NVATS5A114PLZ is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.



DPAK (Single Gauge) / ATPAK CASE 369AM ISSUE O

DATE 29 FEB 2012





Pin2 is idle pin with electrical designation only carried

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